NSN 5961-01-124-2161



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-124-2161 **Inclosure Material:** Glass and metal **Overall Length:** 0.315 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.220 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Terminal Circle Diameter:** 0.035 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.5 reverse voltage, instantaneous **Current Rating Per Characteristic:** 79.00 amperes peak pulse current **Power Rating Per Characteristic:** 1500.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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